Version 2.11, May 2005

Datasheet

DS-FanControl-TDA21801

TDA21801

Authors: E. Chang 1)

G. Bernacchia 2)

N. Florio 2)

R. Pittassi 2)

G. Capodivacca 2)

Published by Infineon Technologies AG

http://www.infineon.com/dcdc

- 1) Villach, Infineon Technologies Austria AG
- 2) Padova, Infineon Technologies Italia S.r.l.

Power Management & Drive



Never stop thinking.

FanControl

Page 1 of 30

DS-FanControl-TDA21801



Contents:

1. Features
2. Applications
3. Pinout and Description
4. General Description
4.1 Block Diagram
4.1.1 External Components Recommendation Values
4.2 Application Circuit
4.3 Absolute Maximum Ratings
4.4 Thermal Characteristic
4.5 Operating Condition10
6 Application Information
6.1 Filter and Amplifier parameters1
6.2 Oscillator parameters1
6.2.1 Electrical Characteristic 13
6.3 Digital Control parameters1
6.3.1 Function of the speed loop 15
6.4 Power Output Stage parameters 1
6.4.1 Electrical Characteristic – Power Output Stage 16
6.5 Speed Value Generation parameters1
6.6 NTC input
6.6.1 Electrical Characteristic - NTC 19
6.7 FCin Input
6.7.1 Electrical Characteristic - FCin 22
6.8 Under Voltage Lockout Block2
6.8.1 Electrical Characteristic – Undervoltage Lockout 24



6.8 FanM	
6.8.1 Electrical Characteristic – FanM Signal	25
7. Outline Dimension:	27
7.1 Footprint Drawing PG-DSO-8	27



TDA21801 Low Cost Fan Speed Controller



1. Features

• Low cost Fan Speed Controller for standard two wires fans

PG-DSO-8

- . No external components for fan speed loop compensation necessary
- Tacho output signal, FanM for speed measurement
- · Adjustable minimum Fan Speed
- External control voltage for fan speed setting
- System Overtemperature Protection for early warning and for system shutdown.

2. Applications

• Fan Speed Control for PC Desktop Silver Box Power Supply

Туре	Package	Marking	Ordering Code
TDA21801	PG-DSO-8	21801	Q67042-S4257

3. Pinout and Description

TOP VIEW

N°	Name	Description
1	FCin	Analog input for external speed control
2	RSin	Sense-resistor input signal
3	TRSOUT	Output to drive the external PNP transistor
4	GND	Ground
5	RC-VCO	VCO adjustment for minimum (minimal) frequency and OTP-psu-shut-down.
6	FanM	Digital output for speed monitoring. Two pulses per revolution signal. Monitor for OTP-early warning and OTP-psu-shut-down warning.
7	NTC	Analog input for temperature sensor (NTC divider)
8	VDD	Supply voltage



4. General Description

The Fan Speed Controller is a fully integrated control with few external components to set up a flexible and low cost application. The device uses the waveform of the current in a standard two-wire fan to detect the speed of revolution and to control it.

The current flowing through the fan is sensed by the shunt resistor connected to **RSin**. For fans with a supply current between 50mA and 400mA, a good value for this resistor is between 0.5 and 1Ω as the maximum input voltage of **RSin** for linear operation is 330mV.

The Pulse Detector circuit creates one internal trigger pulse at every commutation of the fan motor. The internal trigger pulse will be processed if the current waveform through the motor shows appropriate variations at the commutation.

Monitoring and warning signal can be used to check the working condition.

Every two internal trigger pulses one is fed to the FanM output to monitor the speed of rotation.

The device controls the speed of revolution. The temperature is measured with the NTC thermistor and according to the voltage on the **NTC** the speed of the fan is set.

In Fig.1 the dependence of the fan speed with the temperature is shown (supposing a minimum speed of 1329 rpm).

The expression of the minimum VCO frequency @ minimum FAN Speed is given by:

$$fvco = \frac{16}{15} * n * P$$

n = Fan speed in rpm.

P = number of pole (Fans in use for desktop PC SMPS are normally 4 poles).



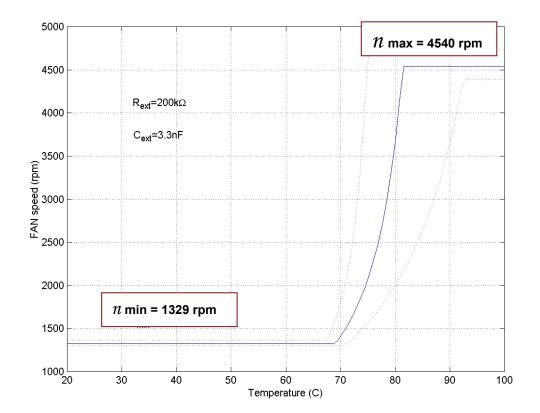


Fig.1 Fan Speed (rpm) vs. Temperature Consider only the typical curve (blue line)



4.1 Block Diagram

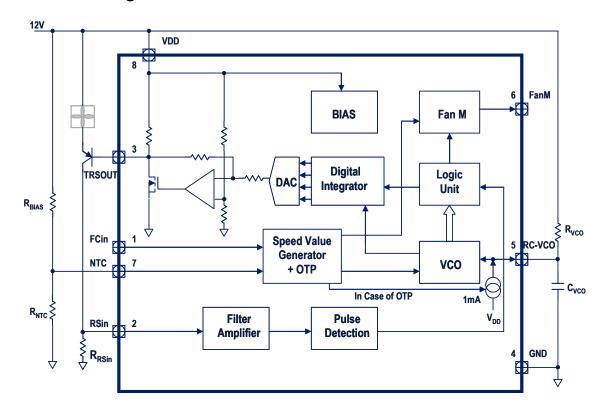


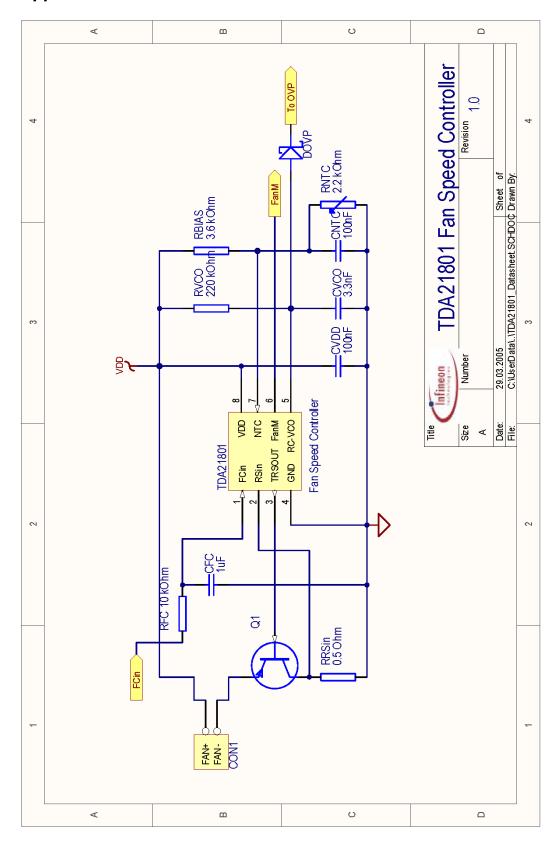
Fig. 2 TDA21801 Block Diagram

4.1.1 External Components Recommendation Values

Name	Description	Typ. Value	Tolerance
R _{BIAS}	Pull up resistor for NTC divider	3.6 kΩ	1%
R _{NTC}	NTC, thermally coupled e.g. with heat sink	2.2 kΩ	5%
R _{RSin}	Shunt Resistor to measure fun current	0.5 Ω ~ 1 Ω	5%
R _{vco}	VCO frequency setting resistor and capacitor	220ΚΩ	1%
C _{vco}		3.3nF	5%



4.2 Application Circuit





4.3 Absolute Maximum Ratings

At Tj = 25 °C, unless otherwise specified

Parameter		Val		
r arameter	Symbol	Min.	Max.	Unit
Voltage supplied to ' VDD ' pin; DC	V _{DD}	-0.3	13.2	
Max voltage on ' TRSOUT ' pin; DC	V_{TRSOUT}	-0.3	13.2	
Max voltage on ' FanM ' pin; DC	V_{FanM}	-0.3	5.5	
Max voltage on ' RSin ' pin; DC	V_{RSin}	-0.3	5.5	V
Max voltage on ' NTC ' pin; DC	V _{NTC}	-0.3	13.2	
Max voltage on ' FCin ' pin; DC	V_{FCin}	-0.3	5.5	
Max voltage on ' RC-VCO ' pin; DC	V_{RC-VCO}	-0.3	13.2	
Junction temperature	TJ	-25	125	°C
Storage temperature	Ts	-55	150	
ESD Rating; Human Body Model			2	kV
ESD Rating; Machine Model			200	V
IEC climatic category; DIN EN 60068-1		55/1	50/56	-

4.4 Thermal Characteristic

Parameter	0 1 1				
, arameter	Symbol	Min.	Тур.	Max.	Unit
Thermal resistance, junction-soldering point (PG-DSO-8)	Rth _{jc-PG-DSO-8}		95		K/W
Thermal resistance, junction-ambient (PG-DSO-8)	Rth _{ja-PG-DSO-8}		125		



4.5 Operating Condition

At Tj = 25 °C, unless otherwise specified

Parameter	Symbol	,	Values		UNIT
T dramotor	oyiii.coi	Min.	Тур.	Max.	0
Voltage supplied to 'VDD' pin; DC	V _{DD}	10.8	12	13.2	
Voltage supplied to 'TRSOUT' pin; DC	V _{TRSOUT}	0		V _{DD}	
FanM	V_{FanM}	0	3.3	5	
RSin	V_{RSin}	0		0.5	V
NTC	V _{NTC}	0		V _{DD}	
FCin	V_{FCin}	0		3.5	
RC-VCO	V _{RC-VCO}	0		V _{DD}	
Junction temperature	Tj	0		100	°C
Ambient temperature	T _a	0		70	
Operating supply current ¹	I_{VDD}		8	12	mA

Without taking into account output current of TRSOUT, FanM and RC-VCO.



6 Application Information

6.1 Filter and Amplifier parameters

The Fan current is measured by a shunt resistor R_{RSin} and connected to the **RSin** pin. This is the input signal to the pre-amplifier with a typical gain of 15 and a typical cut off frequency of 20k Hz and -6 dB/ octave.

Only an input signal between 40mV and 330mV will be properly detected and processed otherwise the recognition of the pulse cannot be guaranteed.

The value of the shunt resistor R_{RSin} has to be chosen according to the current of the fan. For example with spike current of 400mA a shunt resistor of typically 0.68 Ω should be used.

At typical operating condition.

Parameter	Symbol Conditions		\	UNIT		
r urumotor	Cymbol	Conditions	Min.	Тур.	Max.	O
			•			
Gain	GRSin	Verified by Design	14.7	15	15.3	
Cutoff frequency	F _{FA}	Verified by Design		20		kHz
RSin pin source current	I _{Rsin}	V _{RSin} = 100m V	0		4	uA

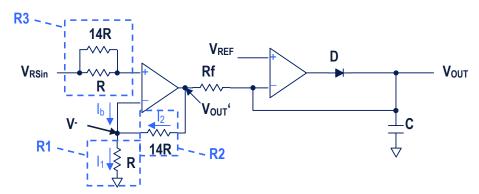


Fig. 3 Analog front end Block Diagram



6.2 Oscillator

The technology of oscillator is similar to the industrial standard 555-timer, with control voltage to increase frequency by a factor of up to 3.4. The external timing resistor, R_{VCO} and capacitor, C_{VCO} set the minimum frequency of \underline{V} oltage \underline{C} ontrolled \underline{O} scillator. The minimum Fan Speed can be adjusted in the range from 750 to 4000 rpm. With tolerance of 3% at rated speed of 1322 rpm, V_{DD} =12V and 25°C (without external components' tolerance), RC-VCO is switched to continuous VDD-output-voltage with open collector output stage if OTP-condition is detected at NTC input. Typical source current up to VDD-5V is 1mA. For this function the anode of a diode can be connected to RC-VCO and the cathode with the 5V input of an external Power-Good circuit. In the case of no OTP the oscillator works between VSP and VSPH and so the diode will not conduct due to lower voltage at Anode compared to Cathode (=5V-input of PowerGood circuit).

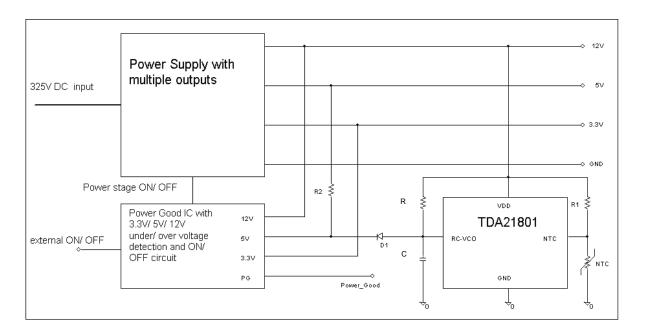


Fig. 4 OTP Application circuit



6.2.1 Electrical Characteristic - Oscillator

At typical operating condition.

Parameter	Symbol	Symbol Conditions	Values			Unit
r arameter	Symbol	Conditions	Min.	Тур.	Max.	Oiiit
Minimum speed control voltage limit	VSP _{fmin}	Highest VSP voltage, which doesn't change the frequency: $f = f_{min}$ (VbD)	9.85	10	10.15	% of V _{DD}
High speed control voltage limit	VSP _{fmax}	Lowest VSP voltage, which produces the maximum frequency: $f = f_{max}$ (VbD)	25.25	25.5	25.75	% of V _{DD}
Upper threshold	VSPH	(VbD)	30.80	31.06	31.35	% of V _{DD}
Minimum VCO frequency	fmin 0	V_{DD} = 12V, Tj=25°C, C = 3.3nF, R= 220kΩ Note 1 V_{NTC} =1.5V 0.42V FCin <0.72V	5.005	5.160	5.315	kHz
Minimum VCO frequency	fmin	V_{DD} = 12V, 0°C <tj<100°c, 1<br="" c="3.3nF," r="220kΩNote">V_{NTC}=1.5V 0.42V <FCin<0.72V</tj<100°c,>	4.902	5.160	5.418	kHz
Maximum VCO frequency	$f_{\sf max}$	V_{DD} = 12V, 0°C <tj<100°c, c="3.3nF," r="220k<math">\Omega ¹⁾ V_{NTC}=1.5V FCin>3V</tj<100°c,>	16.55	17.80	19.05	kHz
External capacitor	C _{VCO}	to have a minimum frequency error better than 5%	1			nF
VCO sink current	I _{VCO sink}	At Vvco=2V	9			mA
VCO source current in OTP condition	I _{VCO source}	25°C <tj<100°c At Vvco=V_{DD}-5V. ²⁾</tj<100°c 	0.7	1	1.45	mA

Verified by Design (VbD)

- (1) Parasitic PAD capacitor is typically 2pF.
- (2) In OTP condition a current generator (MOS current mirror is turned on).



The control loop regulates the fan rotation to a reference frequency. This reference is provided by the internal voltage controlled oscillator. The basic architecture of the VCO is the standard 555 topology. The minimum frequency setting is fixed by an external RC network. The voltage across C is forced to oscillate between the two thresholds V_{SPH} and V_{SP} . The period of oscillation is given by the expression:

$$T_S = T_{ch\, \mathrm{arg}\, e} + T_{disch\, \mathrm{arg}\, e} = RC \ln \left(\frac{V_{DD} - V_{SP}}{V_{DD} - V_{SPH}} \right) + 500 ns$$

Discharging the capacitor is achieved through an internal pull-down transistor. The discharge time is constant and very short compared to the RC time constant. The advantage of this topology is to be insensitive to variations on V_{DD} if the thresholds V_{SP} and V_{SPH} are directly derived from the V_{DD} itself

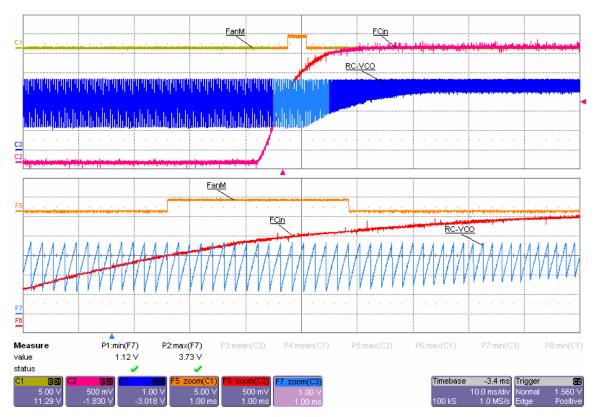


Fig. 5 RC-VCO Valley Voltage At Minimum and Maximum Frequency



6.3 Digital Control parameters

6.3.1 Function of the speed loop

The VCO sets the length of the **FanM** pulse ($T_{FanM} = 16*Tvco$). The length of this pulse is fixed for fixed VCO frequency. The speed loop tries to keep the **FanM** duty cycle of 12.5% stable. For fixed VCO frequency this means that the fan speed is stable. If the VCO frequency is increased, the **FanM** pulse length T_{FanM} is decreased, so with the previous fan speed the duty cycle is lower than 12.5%.

The speed loop then increases the fan speed to achieve 12.5% duty cycle. This happens by reducing **TRSOUT**.

If the duty cycle is too high, this means the **FanM** frequency and fan speed is too high, the **TRSOUT** output is increasing (voltage across fan is decreasing).

If the duty cycle is too low, this means the **FanM** frequency and fan speed is too low, the **TRSOUT** output is decreasing (voltage across fan is increasing). At power-on and every time the fan is turned on starting from not rotating condition the applied voltage on **TRSOUT** is 6.8V referenced to V_{DD} .

6.4 Power Output Stage parameters

The output of the DAC is amplified to the output TRSOUT.

The power output stage is connected with an external transistor to control the fan. There is an intentional internal coupling of fast V_{DD} supply voltage variations to the output **TRSOUT** to keep the voltage across the fan stable. The ratio between supply variations and voltage variations across V_{DD} -**TRSOUT** is expressed as PSRR in the table below.



6.4.1 Electrical Characteristic – Power Output Stage

At typical operating condition.

Parameter	Symbol	Conditions		Values		Unit
r arameter	Syllibol		Min.	Тур.	Max.	Oint
Output saturation	V _{TRSsat}	Isink = 20m A			0.4	V
voltage		TOTAL ZOTATA			0.1	•
Maximum output voltage	V _{TRSmax}		V _{DD} -1		V _{DD}	V
Startup Voltage	V _{TRSstart}	TRSOUT to V _{DD} voltage	6.46	6.8	7.28	V
Negative slew rate for	S 1	E fp - 5 160k Hz		-1.17		
minimum VCO speed	Olrn_fn0 '	$S_{lm_fn0}^{1}$ $F_{VCO} = fn = 5.160k Hz$		-1.17		V/s
Positive slew rate	S _{Irp}		3*Slrn	3*Slrn	3*Slrn	
Output sink current	I _{sink}	V _{TRSOUT} = 1 V	30	50		mA
Power Supply Rejection	PSRR	TRSOUT refered to V _{DD} ;	-20	-40		dB
Ratio	FUNN	Freq=20k Hz	-20	-40		ub

³Negative slew rate meaning decreasing of the V_{TRSout} and increasing of the voltage across the fan. Value defined in order to have a stable global loop



6.5 Speed Value Generation parameters

This block generates the lower threshold for the oscillator: increasing the lower threshold the frequency of the VCO is increased as well. This threshold is given by the highest value of the NTC amplifier output, FCin amplifier output and VSP_{nmin} and it is limited to VSP_{nmax}. For \mathbf{V}_{DD} =12V and typical values following limits are valid:

 V_{FCin} < 2.9% V_{DD} : fan stops if the voltage at NTC is higher than 9% of V_{DD} . If the voltage of the NTC decreases below 9% of V_{DD} , the speed of the VCO is controlled by the voltage at the NTC pin. When the NTC increase back (in case of decreasing temperature) the VCO is controlled by the NTC up to 10% of V_{DD} . If the 'NTC' input voltage is increased above 10% of V_{DD} , the fan is turned off again. 2.9% V_{DD} < V_{FCin} < 7.5% V_{DD} : fan speed is controlled only by NTC (If the pin FCin is open, the open pin voltage is V_{FCopen} = 5.4% V_{DD} typical)

7.5% V_{DD} < V_{FCin} : VCO and fan speed are controlled by the highest between NTC amplified output or FCin amplified output.

V_{FCin} > 23% V_{DD}: VCO oscillator is forced to work at max speed

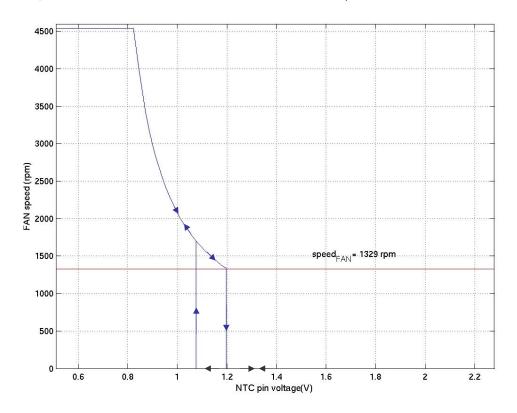


Fig. 6 FAN speed vs. NTC pin voltage (FCin < 2.9% of V_{DD})



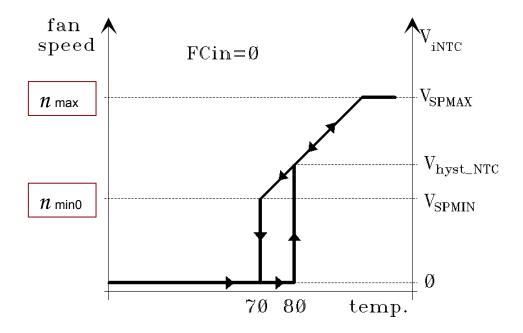


Fig. 7 FAN speed vs. temperature (FCin < 2.9% of $V_{\rm DD}$)

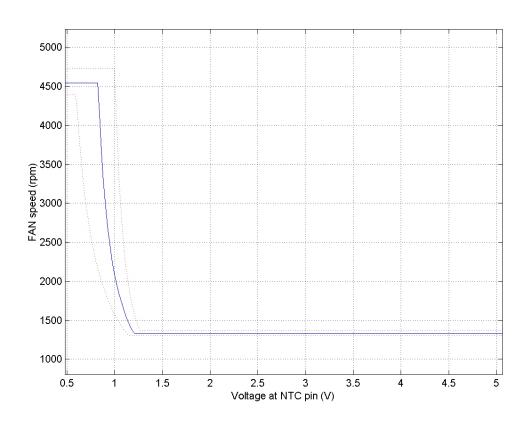


Fig. 8 FAN speed vs. NTC pin voltage (2.9% of V_{DD} <Fcin < 7.5% of V_{DD})



6.6 NTC input

The analog input for NTC divider gives speed information to the VCO (as indicated before) and detects two over temperature conditions for **RC-VCO** output and **FanM** output and **TRSOUT** output:

a) OTP-early-warning condition

This condition is detected, if the **NTC** input goes below V_{NTC_EW} (with a certain hysteresis V_{Hyst_EW}). In this case the **FanM** signal will be inverted to give a warning signal to the PC-system that the power supply is becoming too hot and soon might be switched off.

Normally the **FanM** signal has a duty cycle of 12.5% or lower. In the case of OTP-early-warning condition this duty cycle will switch to 87.5% or higher. This can be easily detected by the PC-system.

b) OTP-psu-shut-down condition

This condition is detected, if the **NTC** input goes below V_{NTC_OT} (with a certain hysteresis V_{Hyst_OT}). In this case actions will be started to shut down the Power supply via the **RC-VCO** pin, also to switch **FanM** to High-level and **TRSOUT** to Low-level.

OTP and Early warning output are filtered and delayed before they become active.

6.6.1 Electrical Characteristic - NTC

At typical operating condition.

Parameter	Symbol	Conditions		Values		UNIT
rarameter	- Cymson	Containons	Min.	Тур.	Max.	
			-			
Input voltage range	V _{NTC}		0		V _{DD}	V
Fan Off NTC voltage	V _{NTC_FanOff}	Rising	9.8	10	10.2	
Fan On NTC voltage	V _{NTC_FanOff}	Falling	8.8	9	9.2	
Early warning						
temperature detection	V _{NTC_EW}	Voltage falling	4.685	4.785	4.885	
level.						
Early warning						% of
temperature detection	V _{Hyst_EW}	To be added to the V _{NTC_EW}	0.19	0.25	0.29	V _{DD}
hysteresis.						
Overtemperature	V	Voltage falling	4.075	4.175	4.275	
detection level -	V _{NTC_OT}	Voltage failing	4.073	4.175	4.213	
Overtemperature	Village OT	To be added to the V _{NTC OT}	0.19	0.25	0.29	
detection hysteresis	V _{Hyst_OT}	TO be added to the VNIC_01	0.13	0.23	0.23	
Voltage gain	G _{NTC}	without external resistor - VbD	-5.2	-5	-4.8	

FanControl

Page 19 of 30

DS-FanControl-TDA21801



Input resistance	R _{NTC}	26	6.3	40	51.4	kΩ
OTP and Early Warning delay	Td _{OTP-EW}			10.4		us

Verified by Design (VbD)

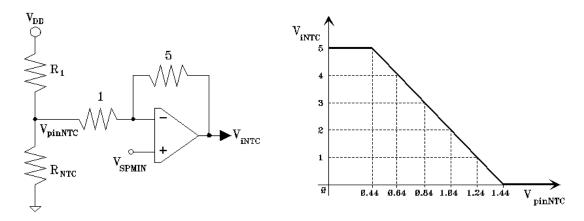


Fig. 9 Amplification of the NTC input signal



6.7 FCin Input

It is an analog input for external speed control. It gives speed information to the VCO and detects fan off condition. If no external voltage source is connected, an internal resistor divider fixes the voltage level at 5.4 % of \mathbf{V}_{DD} . FCin signal is processed in order to make the compare the **FCin** signal with the NTC one. See Fig. 9

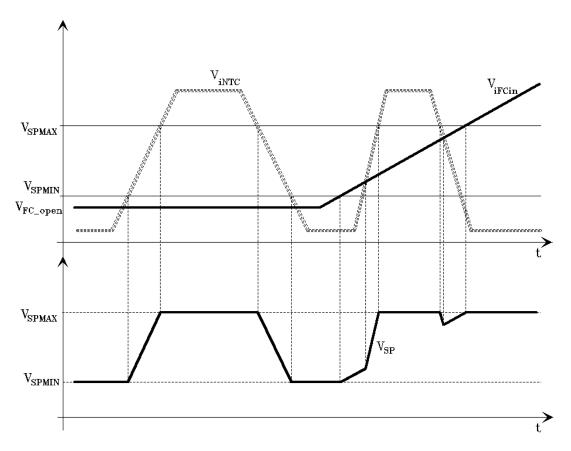


Fig. 10 NTC and FCin signal processing



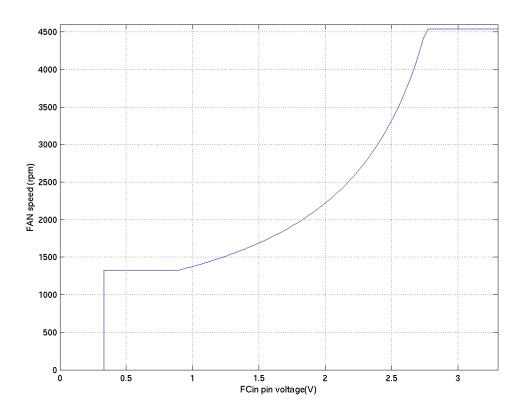


Fig. 11 FAN speeds vs. FCin pin voltage (FCin falling and NTC >10% of $V_{\rm DD}$)

6.7.1 Electrical Characteristic - FCin

At typical operating condition.

Parameter	Symbol	CONDITIONS	V alues			UNIT	
, aramotor	- Cymson	CONDITIONS	Min.		Max.		
OFF voltage limit	V_{FCoff}	Voltage Falling	2.32	2.9	3.48		
OFF voltage limit	W	To be added to the V _{FCoff}	0.3	0.4	0.5		
Hysteresis	V _{FCoff-Hyst}	TO be added to the VFCom					
Voltage limit for	V_{FCmin}		6	7.5	9	% of	
minimum speed	V FCMIN			7.5		V_{DD}	
Voltage limit for	V _{FCmax}		20.7	23	25.3		
maximum speed	V FCmax			25			
Open pin voltage	V _{FC open}		5.1	5.4	5.7		
Input resistance	R _{FC}		100	160		kΩ	

FanControl

Page 22 of 30

DS-FanControl-TDA21801



6.8 Under Voltage Lockout Block

At the power ON/OFF, until the V_{DD} is below 3V the **FanM**, **RC-VCO** and **TRSOUT** pins are all set up to high impedance state (oscillation and OTP warning not allowed). When V_{DD} is crossing between 3 and 7V, **FanM** is switched to Low level, OTP is still not activated and **TRSOUT** pulled up to V_{DD} .

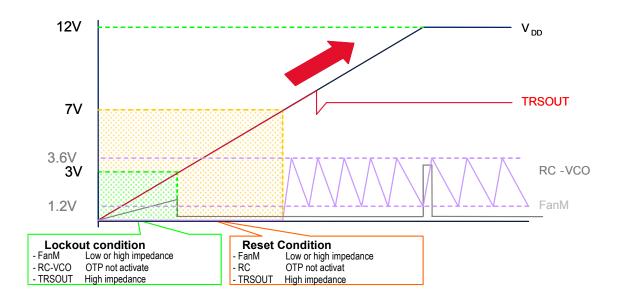


Fig.12 Power Up main waveforms transitory

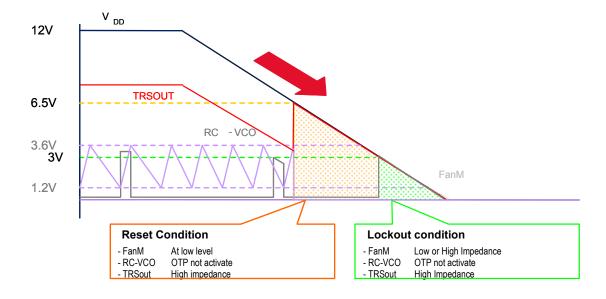


Fig.13 Power Down main waveforms transitory



6.8.1 Electrical Characteristic – Undervoltage Lockout

At typical operating conditions

Parameter	Symbol	CONDITIONS	V alues			U nit
runameter	Cymbol	CONDITIONS	Min.	Тур.	Max	
Lockout Mode Voltage Limit	V _{TLOCK}	slew rate < 5V/ms			3	
Reset Mode Limit Voltage for rising transient	V _{RH}			7	8	V
Hysteresis	Hyst		-0.46	-0.58	-0.7	



6.8 FanM

The **FanM** is a digital output to show the fan speed. The output is an open drain MOSFET with internal pull up and pull down to have same behavior like a 3.3V pull up of 10K.

If there is no OTP-condition detected by the analogue-speed-value block, the **FanM** signal with running fan will have a duty cycle of 12.5% in steady state condition and if the fan is able to run at the loop speed). If the fan is not able to run at the loop speed the duty cycle is lower than 12.5%.

The **FanM** signal is generated to give two pulses per revolution for a four poles fan. Each of the 2 pulses has the same time length of t = 16 / frequency of VCO

There are 2 exceptions:

a) FanM output with OTP-early-warning condition at NTCin-pin:

This condition is detected, if the **NTC** input goes below V_{NTC_EW} (with a certain hysteresis V_{Hyst_EW}). In this case the FanM-signal will be inverted to give a warning to the PC-system, that the power supply is becoming too hot and soon might be switched off.

In this case the FanM duty cycle will switch to 87.5% or higher.

b) FanM output with OTP-psu-shut-down condition at NTCin-pin:

FanM goes to continuous HIGH-position = open Drain MOSFET off. This is a way that an external control system can detect that there is an OTP condition. This signal is a static signal, because the RC-VCO pin will also be used as OTP output. This will stop the oscillator.

6.8.1 Electrical Characteristic – FanM Signal

At typical operating conditions

Parameter	Symbol	Conditions		Values		
	Symbol	Min		Тур.	Max.	Unit
	1					
Output voltage high	V _{FanM_H}	Generated from V _{DD} =12 V	26.5	26.8	27.1	%of
	▼ Fanivi_H	Ocherated Horn VDD-12 V	20.0			V_{DD}
Output voltage low	V _{FanM_L}	I _{sink} =6m A			0.4	V
Output impedance	R _{FanM}		6.6	10	12.8	kΩ



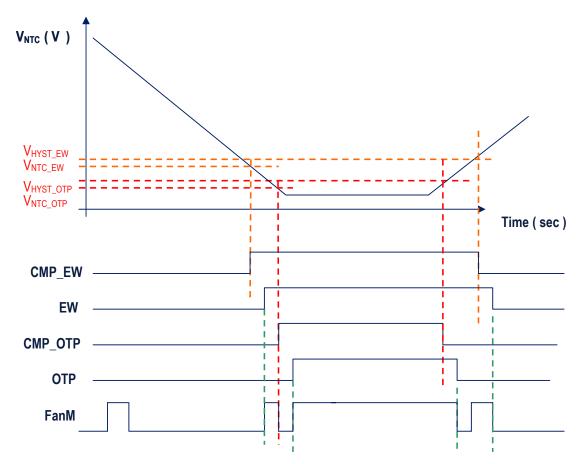
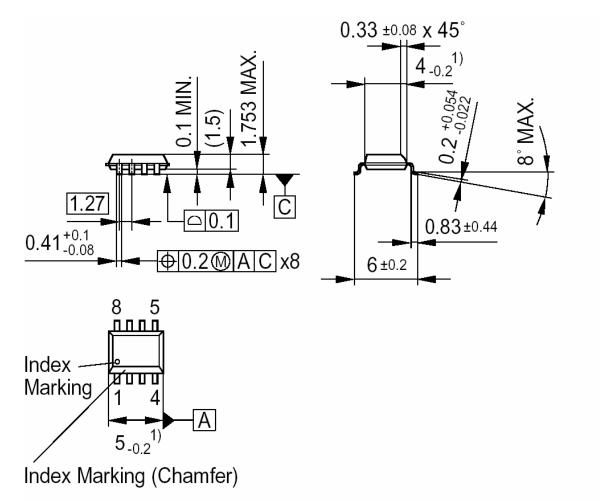


Fig. 14 Signal of the FanM vs NTC pin voltage

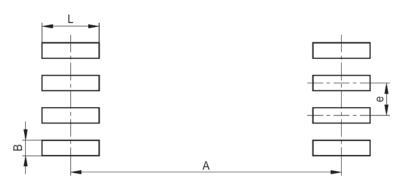


7. Outline Dimension:



¹⁾ Does not include plastic or metal protrusion of 0.15 max. per side

7.1 Footprint Drawing PG-DSO-8



е	; A L		В	
1,27 mm	5,69 mm	1,31 mm	0,65 mm	



Revision History							
Datasheet DS-FanControl-TDA21801							
Actual Relea	ise: V2.11	Date: 06.05.2005	Previous Release:V2.1	Date: 30.03.2005			
Page of	Page of	Subjects changed since last release					
actual Rel.	prev. Rel.						
13	13	Add test condition "2	5°C <tj<100°c" ivco-soเ<="" td="" to=""><td>irce.</td></tj<100°c">	irce.			
20	20	R _{NTC} Tolerance chang "min=26.3kΩ,max=51	es from "min=30kΩ,max=5 .4kΩ"	0kΩ" to			
25	25	R _{FANM} Tolerance chan "min=6.6kΩ,max=12.8	ges from "min=7.5kΩ,max: ßkΩ"	=12.5kΩ" to			

For questions on technology, delivery and prices please contact the Infineon Technologies Offices in Germany or the Infineon Technologies Companies and Representatives worldwide: see the address list on the last page or our webpage at

http://www.infineon.com/DCDC

We listen to Your Comments

Any information within this dokument that you feel is wrong, unclear or missing at all?

Your feedback will help us to continously improve the quality of this dokument.

Please send your proposal (including a reference to this dokument) to:

mcdoku.comment@infineon.com



Edition 2004-09-03

Published by Infineon Technologies AG,

St.-Martin-Strasse 53,

D-81541 München

© Infineon Technologies AG 2004.

All Rights Reserved.

FanControl

Page 28 of 30

DS-FanControl-TDA21801



Attention please!

The information herein is given to describe certain components and shall not be considered as warranted characteristics. Terms of delivery and rights to technical change reserved.

We hereby disclaim any and all warranties, including but not limited to warranties of non-infringement, regarding circuits, descriptions and charts stated herein. Infineon Technologies is an approved CECC manufacturer.

Information

For further information on technology, delivery terms and conditions and prices please contact your nearest Infineon Technologies Office in Germany or our Infineon Technologies Representatives worldwide (see address list).

Warnings

Due to technical requirements components may contain dangerous substances. For information on the types in question please contact your nearest Infineon Technologies Office.

Infineon Technologies Components may only be used in life-support devices or systems with the express written approval of Infineon Technologies, if a failure of such components can reasonably be expected to cause the failure of that life-support device or system, or to affect the safety or effectiveness of that device or system. Life support devices or systems are intended to be implanted in the human body, or to support and/or maintain and sustain and/or protect human life. If they fail, it is reasonable to assume that the health of the user or other persons may be endangered.



INFINEON TECHNOLOGIES AG Sales Offices Worldwide *

Infineon Technologies Austria AG Operngasse 20b/31

A-1040 Wien

T (+43) 1-58 7-70 70 0 Fax (+43) 1-58 7-70 70 20

Australia

Siemens Ltd.

885 Mountain Highway Bayswater, Victoria 3153 T (+61) 3-97 21 21 11

Fax (+61) 3-97 21 72 75 Belgium/Netherlands

Infineon Technologies Holding B.V. Sales Division Westhlaak 32

3012 KM Rotterdam

T (+31) 10 -2 17 68 00 Fax (+31) 10 -2 17 68 19

Brazil

Infineon Technologies South America Ltda.

Avenida Mutinga,3800-Prédio 3

05110-901 São Paulo-SP T (+55) 11-39 08 25 64

Fax (+55) 11-39 08 27 28

Canada

Infineon Technologies Corporation 340 March Road, Suite 301

Canada.Ontario K2K 2E2 T (+1) 6 13-5 91 38 35

Fax (+1) 6 13-5 91 89 54

Infineon Technologies International Trade (Shanghai) Co., Ltd Beijing Representative Office 12th Floor, Quantum Plaza No.27 Zhichun Road, Haidian Distric,

Beijing 100083,

People's Republic of China T (+86) 10 82 35 61 18 Fax (+86) 10 82 35 54 74

Infineon Technologies Hong Kong Ltd, Hong Kong Office 302 Level 3 Festival Walk 80 Tat Chee Avenue, Kowloon Tong

Hong Kong T (+852) 28 32 05 00 Fax (+852) 28 27 97 62

Infineon Technologies International Trade (Shanghai) Co., Ltd No.8, Lane 647, Songtao Road Zhangjiang Hi-Tech Park Pudong, Shanghai, China

Infineon Technologies International Trade (Shanghai) Co., Ltd Shenzhen Office Room 1501-05, Block A Tian An International Building Renmin Nan Road

Shenzhen 518001, China T (+86) 7 55 -2 28 91 04 Fax (+86) 7 55 -2 28 02 17

Germany

Infineon Technologies AG Siemensstraße 31-33 **71254 Ditzingen/Stuttgart** T (+49) 71 56 -1 79 19 10 Fax (+49) 71 56 -1 79 19 90

Infineon Technologies AG Völklinger Straße 4 40219 Düsseldort T (+49) 2 11 -20 95 49 0 Fax (+49) 2 11 -20 95 49 60

Infineon Technologies AG Naegelsbachstraße 26 91052 Erlangen Г (+49) 91 31 97 00 10 Fax (+49) 91 31 97 00 99

Infineon Technologies AG Paderborner Straße 1 30539 Hannovei T (+49) 5 11 87 65 62 0 Fax (+49) 5 11 87 65 62 90

Infineon Technologies AG Rosenheimer Straße 116 81669 München T (+49) 89 23 40 Fax (+49) 89 23 42 46 94

Infineon Technologies AG Südwestpark 65 **90449 Nürnberg** T (+49) 9 11 -2 52 93 0 Fax (+49) 9 11 -2 52 93 93

Infineon Technologies Nordic A/S Herlev Hovedgade 201A DK 2730 Herlev

T (+45) 44 50 77 00 Fax (+45) 44 50 77 01

Finland

Infineon Technologies Nordic OY Linnouitustie 4A P.O. BOX 276

FIN-02601 Espoo

T (+3 58) 10 -6 80 84 00 Fax (+3 58) 10 -6 80 84 01 France

Infineon Technologies France SAS 39 – 47, Bd. Ornano

93527 Saint-Denis CEDEX2 T (+33) 1 48 09 72 00 Fax (+33) 1 48 09 72 90

India

Infineon Technologies India Pvt. Ltd. 10th Floor, Discoverer Building International Technology Park Whitefield Road

Bangalore 560 066, India T (+91) 80 8 41 00 17/18 Fax (+91) 80 8 41 00 12

Ireland

Infineon Technologies Ireland Ltd. 69 Fitzwilliam Lane

Dublin 2. Ireland T (+35) 31 79 99 500 Fax (+35) 31 79 99 501

Israel Nisko I td

2A, Habarzel Street Tel Aviv 69710, Isreal T (+9 72)3 -7 65 73 00 Fax (+9 72)3 -7 65 73 33

Italy Infineon Technologies Italy S.r.I. Via Vipiteno 4

20128 Milano, Italy T (+39) 022 52 04 1 Fax (+39) 022 52 04 43 95

Infineon Technologies Japan K.K. Takanawa Park Tower 8F/9f/12F/17F 3-20-14, Higashi-Gotanda

Shinagawa-ku Tokyo 141-0022, Japan T (+81) 3 54 49 64 11 Fax (+81) 3 54 49 64 01

Infineon Technologies Korea Co., Ltd..

Room No. 2&3,9th floor Daelim Acrotel Building 467-6 Dokock-Dong, Kangnam-Gu

Seoul, Korea 135-971 T (+82) 23 46 00 900 Fax (+82) 23 46 00 901/902

Malaysia Infineon Technologies (M) SDN BHD Krystal Point II

1-4-11/12, Lebuh Bukit Kecil 6 11900 Bayan Lepas Penang, Malaysia T (+60) 46 44 77 66

Fax (+60) 46 41 48 72 **New Zeland**

Siemens Components 300 Great South Road Greenland, Auckland

T (+64) 95 20 30 33 Fax (+64) 95 20 15 56

Portugal

Siemens S A

OG Componentes Electronicos Rua Irmaos Siemens,1 Alfragide

2720-093 Amadora

T (+351) 21-4 17 85 90 Fax (+351) 21-4 17 80 83

Russia

INTECH electronics ul.Smolnaya,24/1203 125 445 Moskva, Russia T (+70) 95 -4 51 97 37 Fax (+70) 95 -4 51 86 08

Singapore

Infineon Technologies Asia Pacific Pte. Ltd.

8 Kallang Sector

349282, Singapore T (+65) 68 40 08 88 Fax (+65) 68 40 xx xx

South Africa Siemens Components

P.O. Box 3438 Halfway House 1685 **Gauteng, South Africa** T (+27) 11 6 52 20 00

Fax (+27) 11 6 52 26 73 Spain

Siemens S A Division Components Ronda de Europa, 5 28760 Tres Cantos-Madrid

T (+34) 91 5 14 71 54 Fax (+34) 91 5 14 70 13

Sweden

Infineon Technologies Nordic AB P.O. Box 46

16493 Kista, Sweden T (+46) 8 7 03 59 00 Fax (+46) 8 7 03 59 01

Switzerland Infineon Technologies Switzerland

Badenerstraße 623 P.O. Box 1570 8048 Zürich T (+41) 1 4 97 80 40 Fax (+41) 1 4 97 80 50

Taiwan

Infineon Technologies Taiwan.Ltd. 12F-1, No.3-2 Yuan Qu. St., Nan Kang Software Park, Taipei Taiwan 115, ROC

T (+8 86)2-2655 7500 Fax (+8 86)2-2655 7501-8

Turkey

Siemens Sanavi ve Ticaret A S Yakacik Yolu No.111 34861 Kartal, Istanbul

T (+90) 21 64 59 28 51 Fax (+90) 21 64 19 31 90 **United Kindom**

Infineon Technologies UK.Ltd. Infineon House Fleet Mill

Minley Road Fleet, Hampshire GU51 2RD T (+44) 12 52 77 22 00 Fax (+44) 12 52 77 22 01

Infineon Technologies North America Corporation 3700 West Parmer Lane, Suite 102 Austin, TX 78727 T (+1) 51 23 41 71 27

Fax (+1) 51 23 41 99 26

Infineon Technologies North America Corporation 8203 Willow Place South, Suite 660 Houston, TX 77070 T (+1) 28 17 74 05 55 Fax (+1) 28 17 74 05 61

Infineon Technologies North America Corporation 485 Route 1 South Iselin, NJ 08830 T (+1) 73 28 55 92 00 Fax (+1) 73 28 55 92

Infineon Technologies North America Corporation 2529 Commerce Drive Kokomo, IN 46902 T (+1) 7 65 -4 56 19 28 Fax (+1) 7 65 -4 56 38 36

Funec Inc. 1050 Route 22 Lebanob, NJ 08833 T (+1) 90 8 -2 36 56 21 Fax (+1) 90 8 -2 36 56 20

Infineon Technologies North America Corporation 21800 Haggerty Road, Suite 112 Northville, MI 48167 T (+1) 2 48 -3 74 08 90 Fax (+1) 2 48 -3 74 25 01

Infineon Technologies North America Corporation 2901 Dallas N. Tollway, Suite 370 Plano, TX 75093 T (+1) 97 23 78 49 46 Fax (+1) 97 24 03 97 89

Infineon Technologies North America Corporation 3000 CentreGreen Way Raleigh, NC 27513 T (+1) 91 96 77 27 00 Fax (+1) 91 96 78 19 34

Infineon Technologies North America Corporation 6170 Cornerstone Ct East, Suite 240

San Diego, CA 92121 T (+1) 85 85 26 22 01 Fax (+1) 85 85 26 22 02

Fax (+1)4 08 -5 01 24 24

Infineon Technologies Corporation 1730 North First Street **San Jose, CA 95112** T (+1)4 08 -5 01 60 00

Infineon Technologies North America Corporation 1901 N. Roselle Road, Suite 1020 Schaumburg, IL 60195 T (+1) 84 78 84 70 09 Fax (+1) 84 78 84 75 99

Infineon Technologies North America Corporation 238 Littleton Road, Suite 200 Westford, MA 01886 T (+1) 97 86 92 05 50 Fax (+1) 97 86 92 23 0

* and representative offices

单击下面可查看定价,库存,交付和生命周期等信息

- >>Infineon Technologies(英飞凌)
- >>点击查看相关商品